

Fig. 3 A layer of dielectric is deposited followed by a lithography patterning to open the area where MIMCap need to be built.

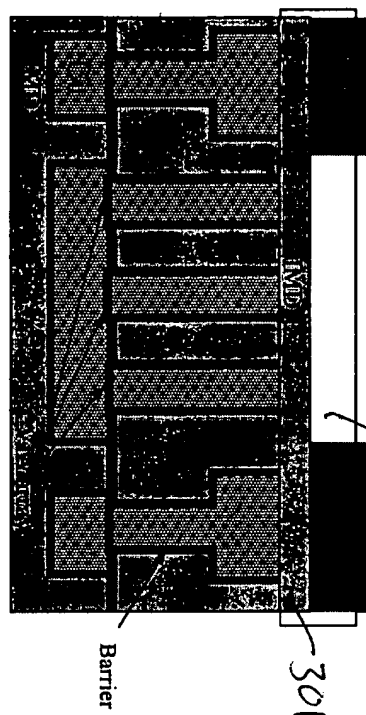


Fig. 4 To selectively etch dielectric and strip the residual resist. This process leaves Cu VIAs stand alone

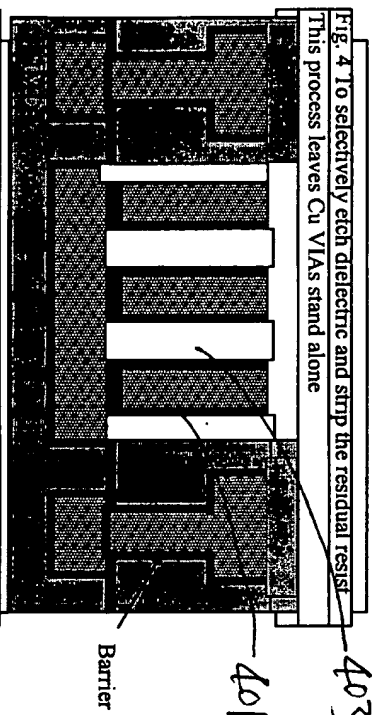


Fig. 5 Top-view of Fig. 4.

